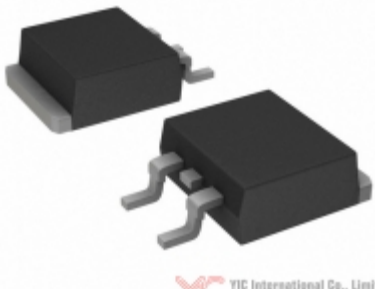







	FQB19N20TM
	Hersteller-Teilenummer: FQB19N20TM
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 19.4A D2PAK
	Datenblätter:  FQB19N20TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 50178 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	FQB19N20TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 19.4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	50178 pcs Stock
Hersteller Standard Vorlaufzeit	8 Weeks
detaillierte Beschreibung	N-Channel 200V 19.4A (Tc) 3.13W (Ta), 140W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 140W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19.4A (Tc)
Rds On (Max) @ Id, Vgs	150 mOhm @ 9.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1600pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB19N20TMCT



















































FQB19N20TM ist neu im Original. Suche FQB19N20TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB19N20TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB19N20TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB19N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 21A D2PAK</p>	 <p>FQB19N20L F FQB19N20L F</p>	 <p>FQB1P50TM Fairchild/ON Semiconductor MOSFET P-CH 500V 1.5A D2PAK</p>	 <p>FQB19N20TM Fairchild/ON Semiconductor MOSFET N-CH 200V 19.4A D2PAK</p>
 <p>FQB1N60TM Fairchild/ON Semiconductor MOSFET N-CH 600V 1.2A D2PAK</p>	 <p>FQB19N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 21A D2PAK</p>	 <p>FQB1N60TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 1.2A D2PAK</p>	 <p>FQB19N20CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A D2PAK</p>

heiße Teile

Mehr

 FQB13N10L	 FQB13N50	 FQB13N50CTM	 D FQB13N50CTM	 FQB140N03L
 FQB14N30TM	 FQB14N30TM	 D FQB16N25TM	 FQB16N25TM	 FQB17P06
 FQB17P10	 FQB17P10TM	 FQB17P10TM	 FQB19N10L	 FQB19N10LTM
 D FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C
 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM	 FQB19N20LTM
 FQB19N20TM	 FQB1N60TM	 D FQB1N60TM	 FQB20N06L	 FQB20N60FTM
 FQB20N60TM	 D FQB22P10	 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085
 FQB24N08TM	 FQB24N08TM	 FQB25N33	 FQB25N33TM	 FQB25N33TM
 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06	 D FQB27P06TM	 FQB27P06TM
 FQB2N50C	 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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